

# PRELIMINARY DATA SHEET

# GD74F32 QUAD 2-INPUT AND GATE

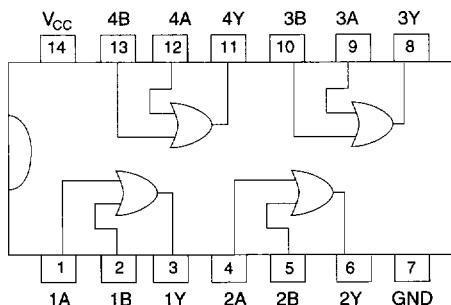
## Description

This device contains four independent 2-input OR gates, each of which performs the Boolean functions  $Y = A \oplus B$  or  $Y = A + B$ .

## Function Table (each gate)

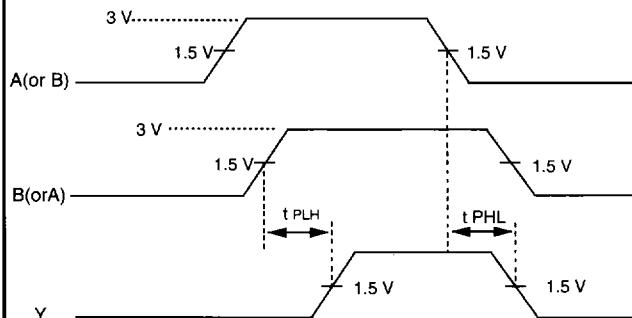
Inputs		Outputs
A	B	Y
H	L	H
L	H	H
H	H	H

## Pin Configuration

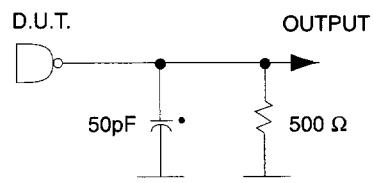


Package Type: 14 DIP, 14 SOP Available

## Waveform Of Functions



## AC Test Circuit



\* Includes jig and probe capacitance

## Input Condition

Frequency : 1.0 MHZ  
 Duty Cycle : 50%  
 Rising Time : 2.5 ns  
 Falling Time : 2.5 ns  
 Amplitude : 0 to 3V

## Absolute Maximum Ratings

- Storage Temperature ..... -65°C to 150°C
- Ambient Temperature Under Bias ..... -55°C to 125°C
- Junction Temperature Under Bias ..... -0.5°C to 175°C
- $V_{CC}$  Voltage ..... -0.5 V to 7.0 V
- Input Voltage ..... -5.0 V to 7.0 V
- Input Current ..... -30 mA to 5.0 mA
- Output Voltage ..... -0.5 V to 5.5 V

Note: Absolute Maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

**Recommended Operating Conditions**

SYMBOL	PARAMETER	MIN	MAX	UNIT
T <sub>A</sub>	Free Air Ambient Temperature	0	70	°C
V <sub>CC</sub>	Supply Voltage	4.5	5.5	V

**AC Characteristics**

SYMBOL	PARAMETER	TEST CONDITION						UNIT	
		TA = 25°C V <sub>CC</sub> = 5.0 V CL = 50 pF			TA = 0 ~ 70°C V <sub>CC</sub> = 5V ± 10% CL = 50 pF				
		Min	Typ	Max	Min	Typ	Max		
t <sub>PLH</sub>	Propagation Delay	3.0	4.2	5.6	3.0	—	6.6	ns	
t <sub>PHL</sub>		3.0	4.0	5.3	3.0	—	6.3	ns	

**DC Electrical Characteristics** over recommended operating free-air temperature range

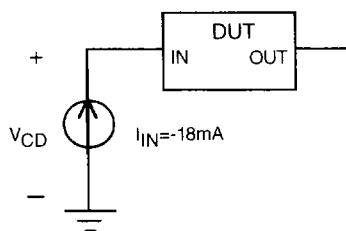
SYMBOL	PARAMETER	TEST CONDITIONS	Min	Typ	Max	UNIT	V <sub>CC</sub>	CIRCUIT
V <sub>IH</sub>	Input High Voltage	—	2.0			V		
V <sub>IL</sub>	Input Low Voltage	—			0.8	V		
V <sub>CD</sub>	Input Clamp Diode Voltage	I <sub>IN</sub> = -18mA			-1.2	V	Min	See FIG. 1
V <sub>OH</sub>	Output High Voltage	I <sub>OH</sub> = -1mA I <sub>OL</sub> = -1mA	2.5 2.7			V	4.5 4.75	See FIG. 2
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 20mA			0.5	V	Min	
I <sub>I</sub>	Input High Current Breakdown Test	V <sub>IN</sub> = 7.0 V			7.0	μA	Max	See FIG. 3
I <sub>IH</sub>	Input High Current	V <sub>IN</sub> = 2.7 V			5.0	μA	Max	
I <sub>IL</sub>	Input Low Current	V <sub>IN</sub> = 0.5 V			-0.6	mA	Max	
I <sub>ILK</sub>	Input Leakage Circuit Current	V <sub>IN</sub> = 4.75 V All other pins grounded			1.9	μA	0.0	See FIG. 4
I <sub>OLK</sub>	Output Leakage Circuit Current	V <sub>OUT</sub> = 150mV All other pins grounded			3.75	μA	0.0	
I <sub>OS</sub>	Output Short Circuit Current	V <sub>OUT</sub> = 0 V	-60		-150	mA	Max	See FIG. 5
I <sub>CCH</sub> I <sub>CCL</sub>	Supply Current	V <sub>OUT</sub> = High V <sub>OUT</sub> = Low		6.1 10.3	9.2 15.5	mA	Max Max	See FIG. 6

\* For I<sub>OS</sub>, Not more than one output should be shorted at a time, and duration should not exceed one second.

## DC Test Circuit

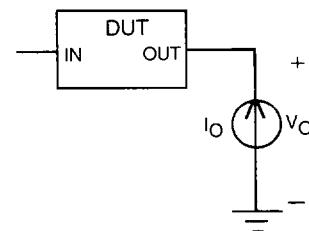
**FIG. 1  $V_{CD}$  Test**

(force  $I_{IN}$  and measure  $V_{CD}$ )



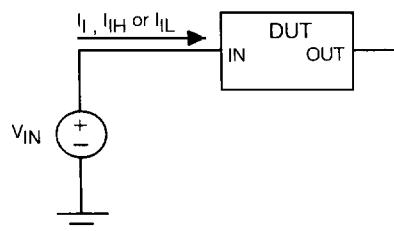
**FIG. 2  $V_{OH}$  &  $V_{OL}$  Test**

(force  $I_O$  and measure  $V_{OH}$  or  $V_{OL}$ )

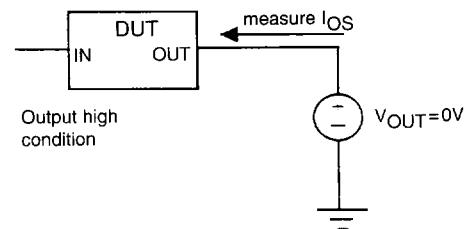


**FIG. 3  $I_L$ ,  $I_{IH}$  &  $I_{IL}$  Test**

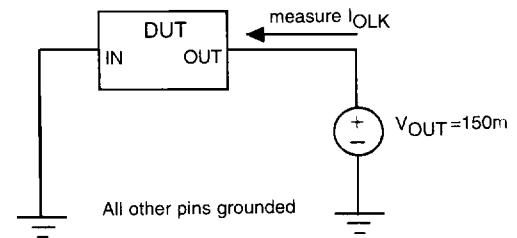
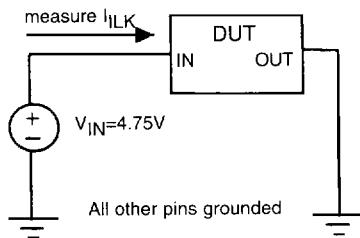
(force  $V_{IN}$  and measure  $I_L$ ,  $I_{IH}$  or  $I_{IL}$ )



**FIG. 5  $I_{OS}$  Test**



**FIG. 4  $I_{ILK}$  Test &  $I_{OLK}$  Test**



**FIG. 6  $I_{CCH}$  Test &  $I_{CCL}$  Test**

